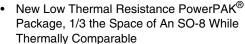


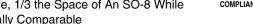
# **Dual N-Channel 100-V (D-S) MOSFET**

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)		
100	0.195 at V <sub>GS</sub> = 10 V	2.5		
	0.230 at V <sub>GS</sub> = 6 V	2.3		

#### **FEATURES**

- Halogen-free Option Available
- TrenchFET® Power MOSFET



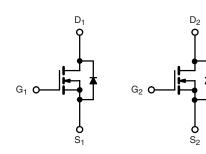




COMPLIANT

#### PWM Optimized **APPLICATIONS**

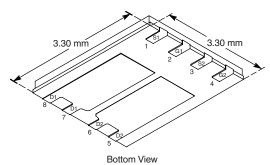
- DC/DC Primary-Side Switch
- 48 V Battery Monitoring



N-Channel MOSFET

N-Channel MOSFET

#### PowerPAK 1212-8



Ordering Information: Si7922DN-T1-E3 (Lead (Pb)-free)

Si7922DN-T1-GE3 (Lead (Pb)-free and Halogen-free)

<b>ABSOLUTE MAXIMUM RATINGS</b>	T <sub>A</sub> = 25 °C, unle	ss otherwise r	noted			
Parameter		Symbol	10 s Steady State		Unit	
Drain-Source Voltage		$V_{DS}$	100		V	
Gate-Source Voltage		$V_{GS}$	± 20		V	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	2.5	1.8		
Continuous Drain Current (1 <sub>J</sub> = 150 °C)	T <sub>A</sub> = 85 °C		1.8	1.3		
Pulsed Drain Current		I <sub>DM</sub>	10		Α	
Avalanche Current	0.1 mH	I <sub>AS</sub>	5 1.25			
Single Avalanche Energy	0.11111	E <sub>AS</sub>			mJ	
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	2.2	1.1	Α	
Mariana Barra Birata di ang	T <sub>A</sub> = 25 °C	P <sub>D</sub>	2.6	1.3	W	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 85 °C		1.4	0.69		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C	
Soldering Recommendations <sup>b, c</sup>			260			

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum lunation to Ambienta	t ≤ 10 s	$R_{thJA}$	38	48	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		77	94	
Maximum Junction-to-Case (Drain)	Steady State	$R_{thJC}$	4.3	5.4	

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

# Vishay Siliconix



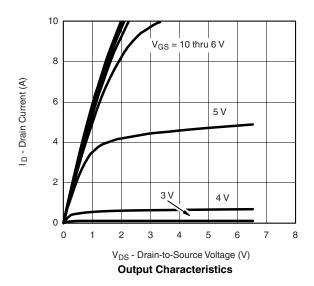
<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C	, unless c	otherwise noted					
Parameter	Symbol	Test Conditions	Min. T		Max.	Unit	
Static							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2.5		3.5	٧	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$	= 0 V, V <sub>GS</sub> = ± 20 V		± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V	1		1		
		$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			5	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	10			Α	
	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 2.5 \text{ A}$	0.162 0.19		0.195		
Drain-Source On-State Resistance <sup>a</sup>		$V_{GS} = 6 \text{ V}, I_D = 2.3 \text{ A}$		0.190	0.230	Ω	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 2.5 A		5.3		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = 2.2 A, V <sub>GS</sub> = 0 V		0.8	1.2	V	
Dynamic <sup>b</sup>			•	•			
Total Gate Charge	$Q_g$			5.2	8		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 2.5 \text{ A}$		1.1		nC	
Gate-Drain Charge	Q <sub>gd</sub>			1.9		1	
Gate Resistance	$R_g$			1.7		Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			7	15		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 50 V, $R_L$ = 50 $\Omega$		11	20		
Turn-Off DelayTime	t <sub>d(off)</sub>	$I_D\cong$ 1 A, $V_{GEN}$ = 4.5 V, $R_G$ = 6 $\Omega$		8	15	ns	
Fall Time	t <sub>f</sub>			11	20		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	$I_F = 2.2 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		40	80		

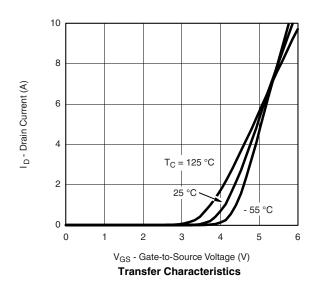
#### Notes

- a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **TYPICAL CHARACTERISTICS** $T_A = 25 \, ^{\circ}C$ , unless otherwise noted



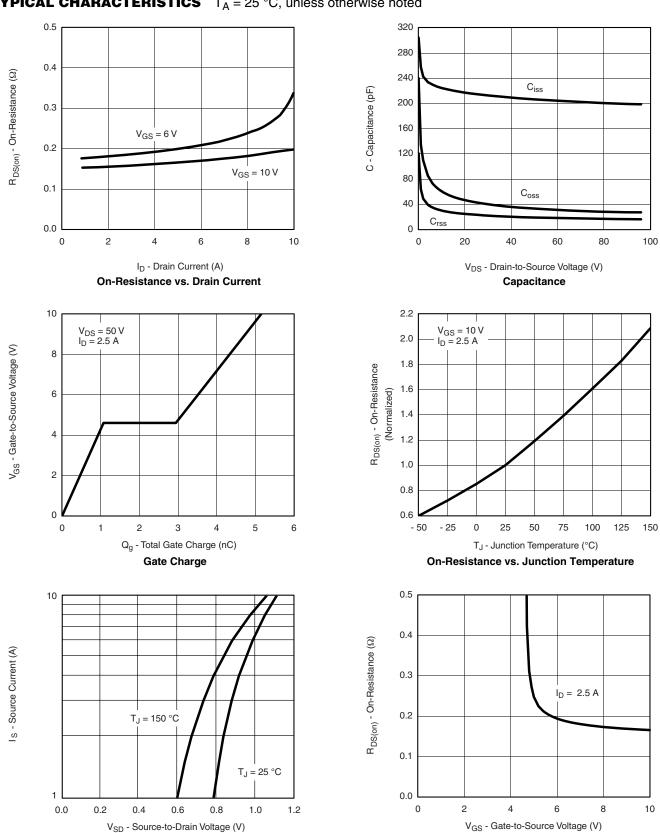








#### **TYPICAL CHARACTERISTICS** $T_A = 25$ °C, unless otherwise noted



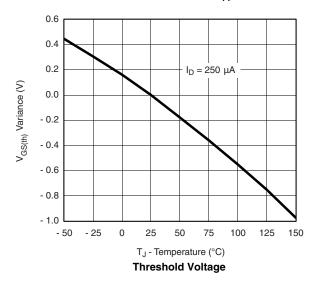
Source-Drain Diode Forward Voltage

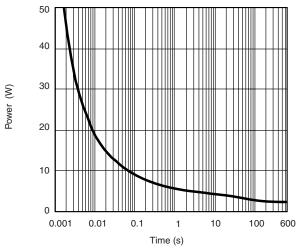
On-Resistance vs. Gate-to-Source Voltage

## Vishay Siliconix

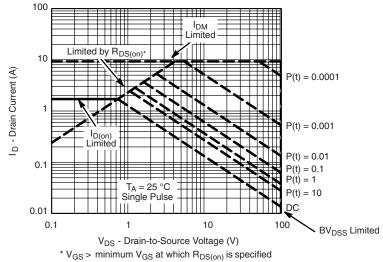
# VISHAY.

#### **TYPICAL CHARACTERISTICS** $T_A = 25 \, ^{\circ}C$ , unless otherwise noted

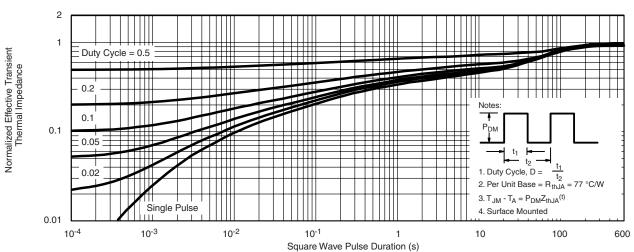




Single Pulse Power, Junction-to-Ambient



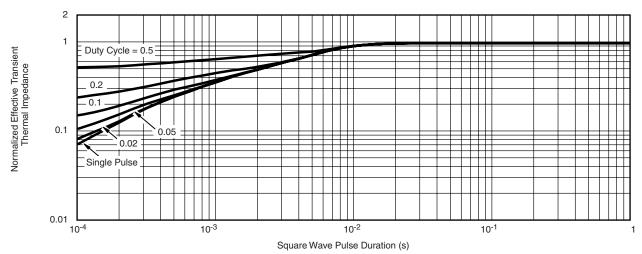
Safe Operating Area, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient



#### **TYPICAL CHARACTERISTICS** $T_A = 25 \, ^{\circ}C$ , unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?72031">http://www.vishay.com/ppg?72031</a>.

Document Number: 72031 S-81544-Rev. E, 07-Jul-08

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